

74LVQ125

Low Voltage Quad Buffer with 3-STATE Outputs

General Description

The LVQ125 contains four independent non-inverting buffers with 3-STATE outputs.

Features

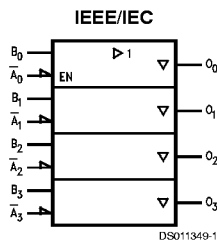
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Guaranteed incident wave switching into 75Ω

Ordering Code:

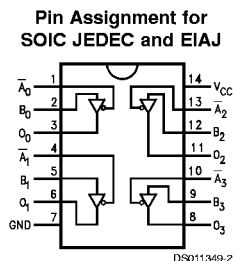
Order Number	Package Number	Package Description
74LVQ125SC	M14A	14-Lead (0.150" Wide) Small Outline Integrated Circuit, SOIC JEDEC
74LVQ125SJ	M14D	14-Lead Small Outline Package, SOIC EIAJ

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\bar{A}_n, B_n$	Inputs
O_n	Outputs

Truth Table

Inputs		Output
$\bar{A}_n$	B_n	O_n
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
Z = HIGH Impedance
X = Immaterial

74LVQ125 Low Voltage Quad Buffer with 3-STATE Outputs

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	–0.5V to +7.0V
DC Input Diode Current (I_{IK})	
$V_I = -0.5V$	–20 mA
$V_I = V_{CC} + 0.5V$	+20 mA
DC Input Voltage (V_I)	–0.5V to $V_{CC} + 0.5V$
DC Output Diode Current (I_{OK})	
$V_O = -0.5V$	–20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V_O)	–0.5V to $V_{CC} + 0.5V$
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
(I_{CC} or I_{GND})	±200 mA
Storage Temperature (T_{STG})	–65°C to +150°C
DC Latch-Up Source or	
Sink Current	±100 mA

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	–40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 3.0V	125 mV/ns

Note 1: The “Absolute Maximum Ratings” are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The “Recommended Operating Conditions” table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V _{CC} (V)	T _A = +25° C		T _A = −40° C to +85° C	Units	Conditions
			Typ	Guaranteed Limits			
V _{IH}	Minimum High Level Input Voltage	3.0	1.5	2.0	2.0	V	V _{OUT} = 0.1V or V _{CC} − 0.1V
V _{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	V	V _{OUT} = 0.1V or V _{CC} − 0.1V
V _{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	I _{OUT} = −50 μA
		3.0		2.58	2.48	V	V _{IN} = V _{IL} or V _{IH} (Note 3) I _{OH} = −12 mA
V _{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	I _{OUT} = 50 μA
		3.0		0.36	0.44	V	V _{IN} = V _{IL} or V _{IH} (Note 3) I _{OL} = 12 mA
I _{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	μA	V _I = V _{CC} , GND
I _{OZ}	Maximum 3-STATE Leakage Current	3.6		±0.25	±2.5	μA	V _I (OE) = V _{IL} , V _{IH} V _I = V _{CC} , GND V _O = V _{CC} , GND
I _{OLD}	Minimum Dynamic (Note 4) Output Current	3.6			36	mA	V _{OLD} = 0.8V Min (Note 5)
I _{OHD}		3.6			−25	mA	V _{OHD} = 2.0V Min (Note 5)
I _{CC}	Maximum Quiescent Supply Current	3.6		4.0	40.0	μA	V _{IN} = V _{CC} or GND
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	3.3	0.6	1.0		V	(Notes 6, 7)
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	3.3	−0.6	−1.0		V	(Notes 6, 7)
V _{IHD}	Maximum High Level Dynamic Input Voltage	3.3	1.7	2.0		V	(Notes 6, 8)
V _{ILD}	Maximum Low Level Dynamic Input Voltage	3.3	1.5	0.8		V	(Notes 6, 8)

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed for 74LVQ.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n – 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}).
f = 1 MHz.

AC Electrical Characteristics

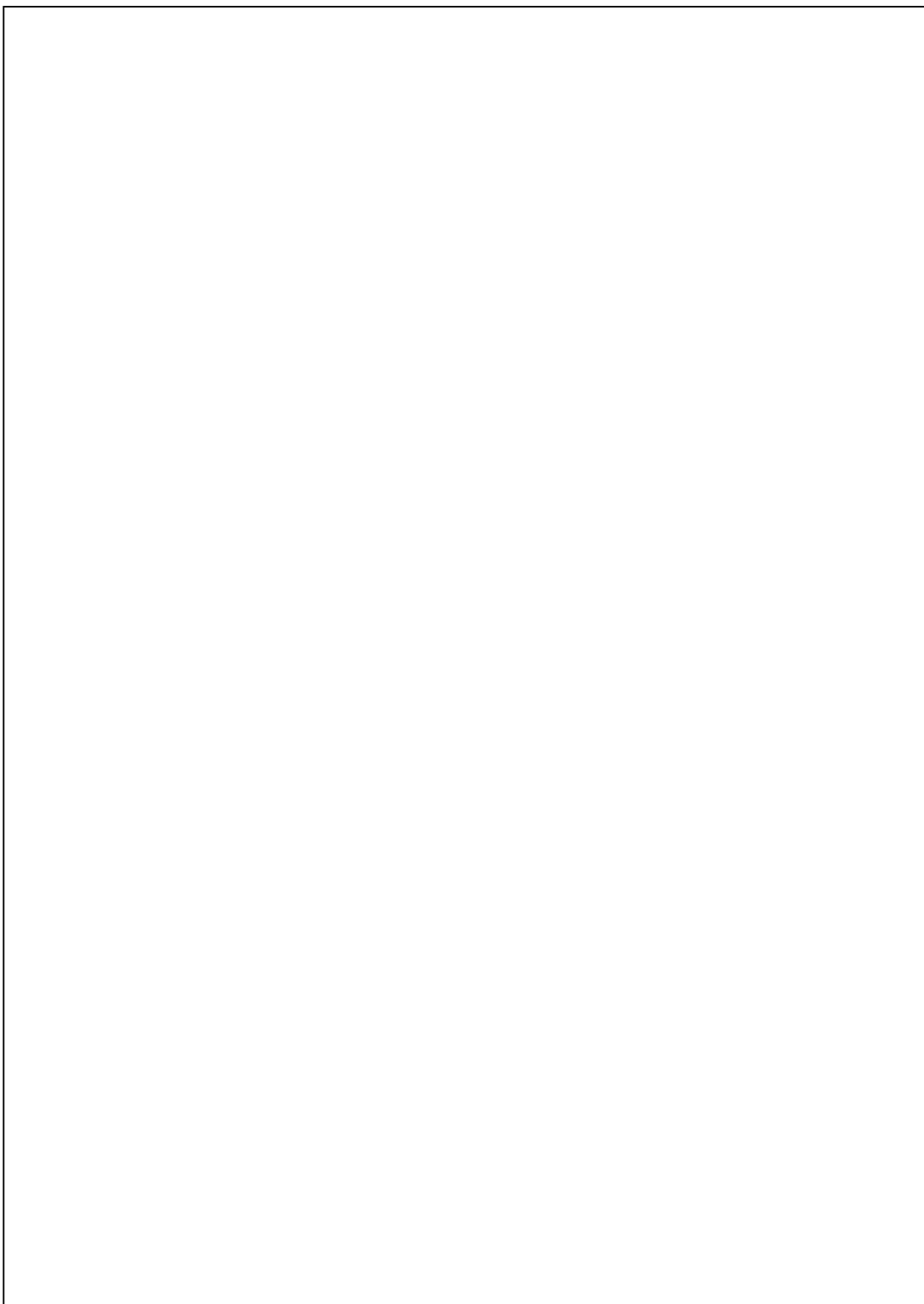
Symbol	Parameter	V _{CC} (V)	T _A = +25° C C _L = 50 pF			T _A = -40° C to +85° C C _L = 50 pF		Units
			Min	Typ	Max	Min	Max	
t _{PLH}	Propagation Delay Data to Output	2.7 3.3 ±0.3	1.0	7.8	12.7	1.0	14.0	ns
t _{PHL}	Propagation Delay Data to Output	2.7 3.3 ±0.3	1.0	7.8	12.7	1.0	14.0	ns
t _{PZH}	Output Enable Time	2.7 3.3 ±0.3	1.0	7.2	14.8	1.0	16.0	ns
t _{PZL}	Output Enable Time	2.7 3.3 ±0.3	1.0	9.0	14.0	1.0	16.0	ns
t _{PHZ}	Output Disable Time	2.7 3.3 ±0.3	1.0	9.0	14.0	1.0	15.0	ns
t _{PLZ}	Output Disable Time	2.7 3.3 ±0.3	1.0	9.0	14.8	1.0	16.5	ns
t _{OSHL} , t _{OSLH}	Output to Output Skew (Note 9) Data to Output	2.7 3.3 ±0.3		1.0	1.5		1.5	ns

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

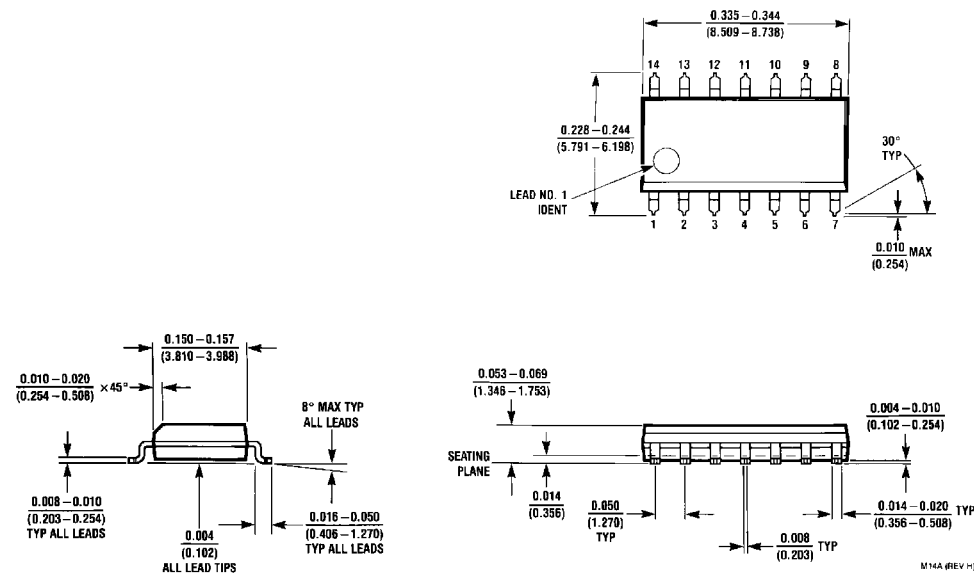
Capacitance

Symbol	Parameter	Typ	Units	Conditions
C _{IN}	Input Capacitance	4.5	pF	V _{CC} = Open
C _{PD} (Note 10)	Power Dissipation Capacitance	34	pF	V _{CC} = 3.3V

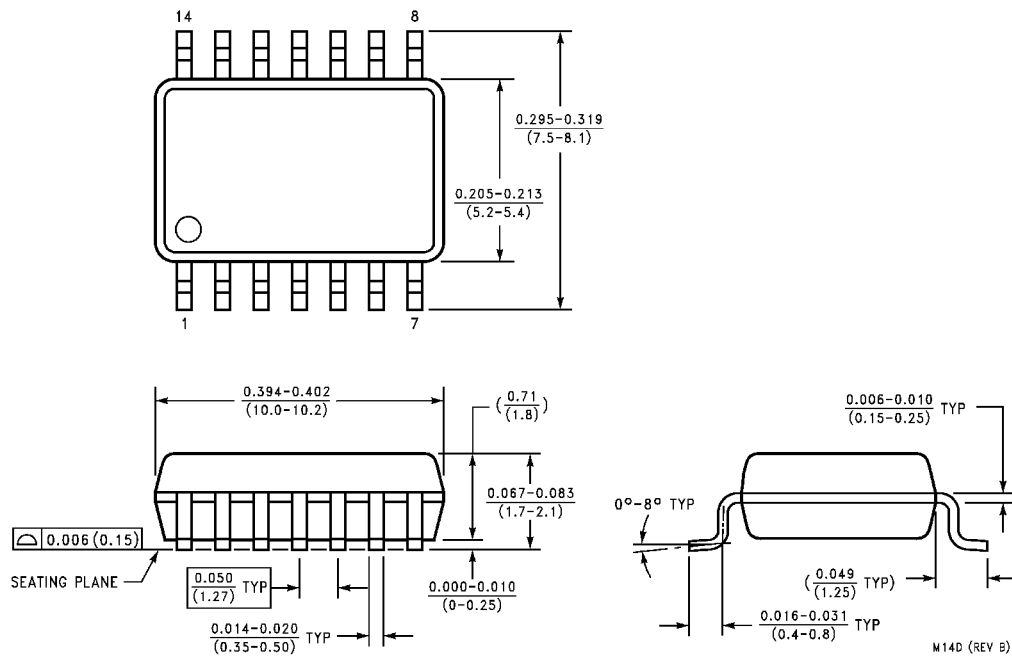
Note 10: C_{PD} is measured at 10 MHz.



Physical Dimensions inches (millimeters) unless otherwise noted



**14-Lead (0.150" Wide) Small Outline Integrated Circuit
Package Number M14A**



**14-Lead Small Outline Package EIAJ
Package Number M14D**